

# BTA306A

## **6A TRIACS**

### DESCRIPTION

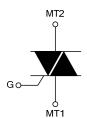
The UTC **BTA306A** is a 6A triacs which can be operated in 3 quadrants only, it uses UTC's advanced technology to provide customers with high commutation performances, etc.

The UTC **BTA306A** is suitable for inductive load switching operations, also can be used in ON/OFF function applications such as induction motor starting circuits, heating regulation, static relays etc.

- (4)Voltage

– (5)Green Package

### SYMBOL



# 1 TO-220F

### ORDERING INFORMATION

Ordering	Package	Pin	Assignr	Packing		
Lead Free	Halogen Free	Fackage	1	2	3	Facking
BTA306AL-x-xx-TF3-T	BTA306AL-x-xx-TF3-T BTA306AG-x-xx-TF3-T		OF MT1 MT2			Tube
Note: Pin Assignment: MT1:	e					
BTA306AL-x-xx-TF3-T	(1) T: Tube					
	(2)Package Type		20F			
	<ul> <li>— (3)Sensitivity and type</li> </ul>	(3) refer to SE	NSITIV	ITY AN	ID TYP	E

(4) 6: 600V, 8: 800V

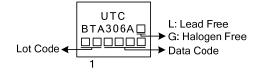
(5) L: Lead Free, G: Halogen Free and Lead Free

### SENSITIVITY AND TYPE

PART NUMBER	VOL	ΓAGE	SENSITIVITY TYPE			
PART NUMBER	600V	800V	SENSITIVIT	TTPE		
BW	$\bigcirc$	0	50mA	SNUBBERLESS		
CW	O	0	35mA	SNUBBERLESS		
SW	$\bigcirc$	0	10mA	LOGIC LEVEL		
TW	$\bigcirc$	0	5mA	LOGIC LEVEL		

O: Available

### MARKING



### TRIAC

### ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	RATINGS	UNIT		
RMS On-State Current (Full Sine Wave)	T <sub>C</sub> =105°C		I <sub>T(RMS)</sub>	6	А
Non Repetitive Surge Peak On-State	F=50Hz	t=20ms	I <sub>TSM</sub>	60	А
Current (Full Cycle TJ initial=25°C)	F=60Hz	t=16.7ms	• 1 3 WI	63	А
I <sup>2</sup> t Value for Fusing	t <sub>P</sub> =10ms		l <sup>2</sup> t	21	A <sup>2</sup> s
Critical Rate of Rise of On-State Current: I <sub>G</sub> =2xI <sub>GT</sub> , tr≤100ns	F=120Hz	TJ=125°C	dl/dt	50	A/µs
Peak Gate Current	t <sub>P</sub> =20µs	TJ=125°C	I <sub>GM</sub>	4	А
Average Gate Power Dissipation		TJ=125°C	$P_{G(AV)}$	1	W
Operating Junction Temperature			ТJ	-40~+125	°C
Storage Junction Temperature		T <sub>STG</sub>	-40~+150	°C	

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

### THERMAL RESISTANCES

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Ambient	θ <sub>JA</sub>	60	°C/W
Junction to Case (AC)	θ <sub>JC</sub>	2.7	°C/W

### ■ ELECTRICAL CHARACTERISTICS (T<sub>J</sub>= 25°C, unless otherwise specified)

### FOR SNUBBERLESS AND LOGIC LEVEL (3 QUADRANTS)

FOR SNUBBERLESS AND LUGIC LEVEL (S QUADRANTS																
PARAMETER	SYMBOL	TEST		TW		SW		CW			BW			UNIT		
FARAIVIETER	STINDOL	CONDITIO	ONS	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
Gate Trigger Current (Note 1)	I <sub>GT</sub>	V <sub>D</sub> =12V R∟=30Ω	1-11-111			5			10			35			50	mA
Gate Trigger Voltage	$V_{\text{GT}}$	RL=3002	-  -			1.3			1.3			1.3			1.3	V
Gate Non-Trigger Voltage	$V_{\text{GD}}$	V <sub>D</sub> =V <sub>DRM</sub> , R <sub>L</sub> =3.3kΩ, T <sub>J</sub> =125°C	1-11-111	0.2			0.2			0.2			0.2			v
Holding Current (Note 2)	Ι <sub>Η</sub>	I⊤=100mA				10			15			35			50	mA
Latching Current	ΙL	I <sub>G</sub> =1.2I <sub>GT</sub>	-    			10 15			25 30			50 60			70 80	mA mA
Critical Rate of Rise of Off-State Voltage (Note 2)	dV/dt	V <sub>D</sub> =67%V <sub>DR</sub> Gate Open, T <sub>J</sub> =125°C	M,	20			40			400			1000			V/µs
Critical Rate of Rise of		(dV/dt)c=0.1 T <sub>J</sub> =125°C	V/µs	2.7			3.5									A/ms
Off-State Voltage at	(dl/dt)c	(dV/dt)c=10 T <sub>J</sub> =125°C	V/µs,	1.2			2.4									A/ms
Commutation (Note 2)		Without Snu Tյ= 125°C	lbber							3.5			5.3			A/ms

Notes: 1. Minimum  $I_{\text{GT}}$  is guaranteed at 5% of  $I_{\text{GT}}$  max.

2. For both polarities of MT2 referenced to MT1.



### ■ STATIC CHARACTERISTICS

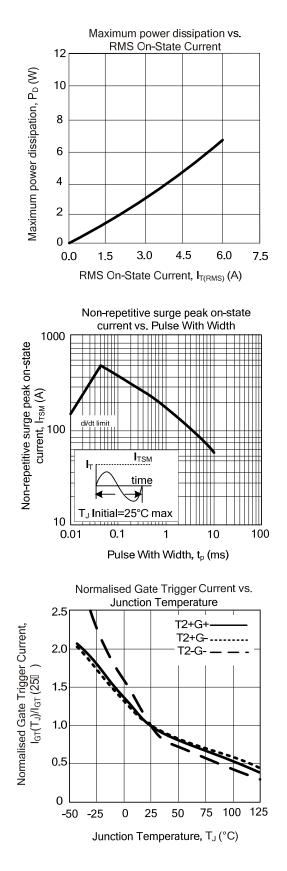
PARAMETER	SYMBOL	TEST CONDITIONS			TYP	MAX	UNIT
Peak On-State Voltage (Note 2)	V <sub>TM</sub>	I <sub>™</sub> =8.5A, t <sub>P</sub> =380µs	TJ=25°C			1.55	V
Threshold Voltage (Note 2)	V <sub>TO</sub>		TJ=125°C			0.85	V
Dynamic Resistance (Note 2)	R <sub>D</sub>		TJ=125°C			60	mΩ
Repetitive Peak Off-State Current	I <sub>DRM</sub>		TJ=25°C			5	μA
	I <sub>RRM</sub>	V <sub>DRM</sub> =V <sub>RRM</sub>	TJ=125°C			1	mA

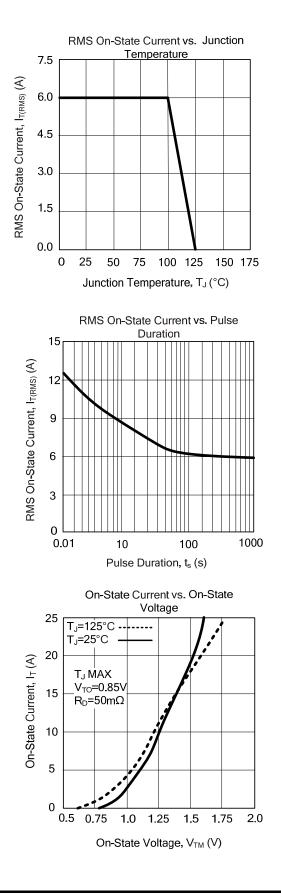
Notes: 1. Minimum  $I_{\text{GT}}$  is guaranteed at 5% of  $I_{\text{GT}}$  max.

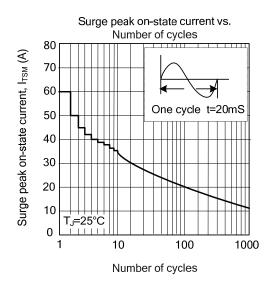
2. For both polarities of MT2 referenced to MT1.



### TYPICAL CHARACTERISTICS







### **TYPICAL CHARACTERISTICS (Cont.)**

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